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Vishay Semiconductors

# Medium Power Silicon Rectifier Diodes, (Stud Version), 12 A



PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	12 A			
Package	DO-4 (DO-203AA)			
Circuit configuration	Single			

## FEATURES

- Voltage ratings from 50 V to 1000 V
- High surge capability
- Low thermal impedance
- High temperature rating
- Can be supplied as JAN and JAN-TX devices in accordance with MIL-S-19500/260
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

VALUES 12 150	UNITS A	
150	20	
	C°	
230	•	
240	A	
260	A <sup>2</sup> s	
240	A-S	
65 to +200	O°	
0 to 1000	V	
	260	

Note

• JEDEC<sup>®</sup> registered values are in bold

### **ELECTRICAL SPECIFICATIONS**

VOLTAGE RATINGS				
TYPE NUMBER	V <sub>RRM</sub> , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE (T <sub>C</sub> = -65 °C TO 200 °C) V	V <sub>R(RMS)</sub> , MAXIMUM RMS REVERSE VOLTAGE (T <sub>C</sub> = -65 °C TO 200 °C) V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE (T <sub>C</sub> = -65 °C TO 200 °C) V	V <sub>RM</sub> , MAXIMUM DIRECT REVERSE VOLTAGE (T <sub>C</sub> = -65 °C TO 200 °C) V
VS-1N1199A	50	35	100	50
VS-1N1200A	100	70	200	100
VS-1N1201A	150	105	300	150
VS-1N1202A	200	140	350	200
VS-1N1203A	300	210	450	300
VS-1N1204A	400	280	600	400
VS-1N1205A	500	350	700	500
VS-1N1206A	600	420	800	600
VS-1N3670A	700	490	900	700
VS-1N3671A	800	560	1000	800
VS-1N3672A	900	630	1100	900
VS-1N3673A	1000	700	1200	1000
VS-1N3624	1000	1200	1400	1000

#### Notes

JEDEC<sup>®</sup> registered values are in bold

• Basic part number indicates cathode to case; for anode to case, add "R" to part number, e.g., 1N1199RA

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COMPLIANT

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FORWARD CONDUCTION						
PARAMETER		SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current at case temperature			180° sinusoidal conduction		12	А
		I <sub>F(AV)</sub>			150	°C
Maximum peak one cycle non-repetitive		tive I <sub>FSM</sub>	Half cycle 50 Hz sine wave or 6 ms rectangular pulse	Following any rated load condition and with rated V <sub>RRM</sub> applied	230	A
			Half cycle 60 Hz sine wave or 5 ms rectangular pulse		240	
surge current	· · ·		Half cycle 50 Hz sine wave or 6 ms rectangular pulse	Following any rated load condition and with V <sub>RRM</sub> applied following surge = 0 V	275	
			Half cycle 60 Hz sine wave or 5 ms rectangular pulse		285	
			t = 10 ms	With rated $V_{RRM}$ applied following surge, initial $T_J = 200 \text{ °C}$	260	A <sup>2</sup> s
Maximum I <sup>2</sup> t for fusing		l <sup>2</sup> t	t = 8.3 ms		240	
Maximum I <sup>2</sup> t for individual			t = 10 ms	With $V_{RRM} = 0 V$ following surge, initial $T_J = 200 \degree C$	370	
device fusing			t = 8.3 ms		340	
Maximum l²√t for individual device fusing		l²√t <sup>(1)</sup>	t = 0.1 ms to 10 ms, $V_{RRM}$ = 0 V following surge		3715	A²√s
Maximum forward voltage drop		V <sub>FM</sub>	I <sub>F(AV)</sub> = 12 A (38 A peak), T <sub>C</sub> = 25 °C		1.35	V
	$V_{RRM} = 50 V$				3.0	-
	V <sub>RRM</sub> = 100 V				2.5	
	$V_{RRM} = 150 V$				2.25	
	$V_{RRM} = 200 V$		Maximum rated $I_{F(AV)}$ and $T_{C}$		2.0	mA
	V <sub>RRM</sub> = 300 V	I <sub>R(AV)</sub> <sup>(2)</sup>			1.75	
Maximum average reverse current	$V_{RRM} = 400 V$				1.5	
	$V_{RRM} = 500 V$				1.25	
	$V_{RRM} = 600 V$				1.0	
	$V_{RRM} = 700 V$				0.9	
	$V_{RRM} = 800 V$				0.8	
	$V_{RRM} = 900 V$				0.7	
V <sub>RRM</sub> = 1000 V					0.6	

#### Notes

• JEDEC<sup>®</sup> registered values are in bold

<sup>(1)</sup> I<sup>2</sup>t for time  $t_x = I^2 \sqrt{t} x \sqrt{t_x}$ 

 $^{(2)}$  Maximum peak reverse current (I\_RM) under same conditions  $\approx 2~x$  rated I\_R(AV)

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum operating case and storage temperature range		T <sub>C</sub> , T <sub>Stg</sub>		-65 to 200	°C
Maximum internal thermal resistance, junction to case		R <sub>thJC</sub>	DC operation	2.0	°C/W
Thermal resistance, case to sink		R <sub>thCS</sub>	Mounting surface, smooth, flat and greased	0.5	
Mounting torque	minimum		Torque applied to nut; non-lubricated threads	1.36 (12)	N · m (lbf · in)
	maximum		Torque applied to hut, non-lubricated threads	1.69 (15)	
	minimum		Taxava applied to put lubricated threads	1.07 (9.45)	
	maximum		Torque applied to nut; lubricated threads	1.30 (11.55)	
	minimum		Targue explicit to device energy lubricated threads	1.17 (10.35)	
	maximum		Torque applied to device case; lubricated threads	1.43 (12.65)	
Approximate weight				7.0	g
				0.25	oz.
Case style	ase style JEDEC® DO-4 (DO-		D-203AA)		

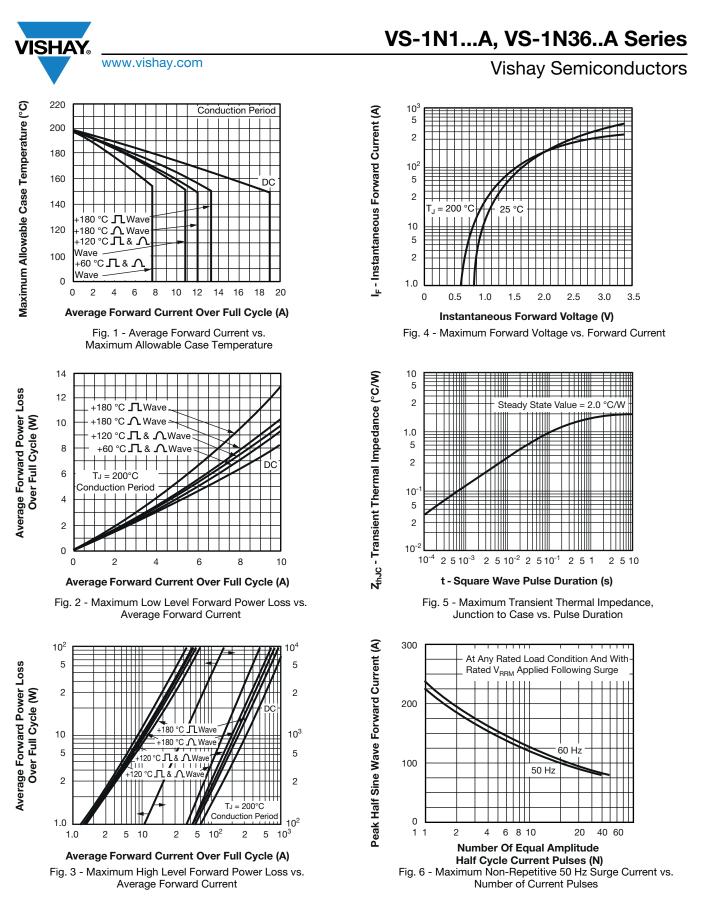
#### Note

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R 0.40 R (0.02)

Ø 6.8 (0.27)

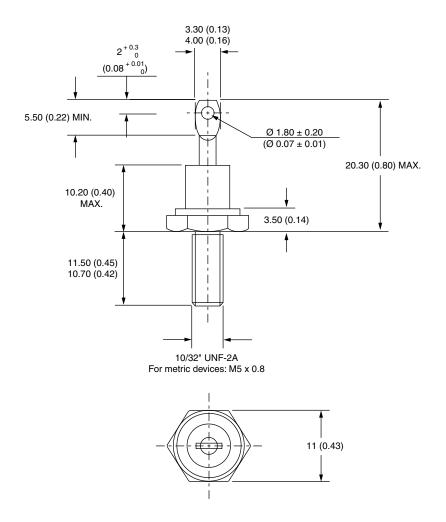
 $0.8 \pm 0.1$ 

 $(0.03 \pm 0.004)$ 



# DO-203AA (DO-4)

### **DIMENSIONS** in millimeters (inches)







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